1. General description

NPN/NPN general-purpose double transistors in a leadless ultra small DFN1412-6 (SOT1268) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: BC857RA NPN/PNP complement: BC847RAPN

2. Features and benefits

- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- · General-purpose switching and amplification
- · Mobile applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor		'				
V_{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	200	mA
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 2 mA; T_{amb} = 25 °C		200	-	450	



45 V, 100 mA NPN/NPN general-purpose double transistors

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	1 7 6	
3	C2	collector TR2	5	(TR1) TR2)
4	E2	emitter TR2		
5	B2	base TR2	3 8 4	É1 B1 C2
6	C1	collector TR1		sym020
7	C1	collector TR1	Transparent top view	
8	C2	collector TR2	DFN1412-6 (SOT1268)	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BC847RA	DFN1412-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268

7. Marking

Table 4. Marking codes

Type number	Marking code
BC847RA	A5

45 V, 100 mA NPN/NPN general-purpose double transistors

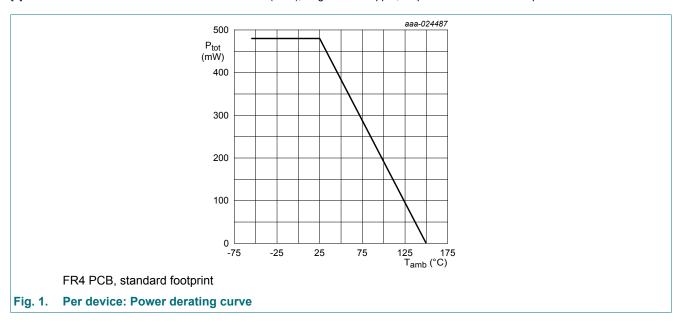
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or			'		
V _{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	45	V
V_{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	200	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device				'		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



45 V, 100 mA NPN/NPN general-purpose double transistors

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W	
Per device	Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

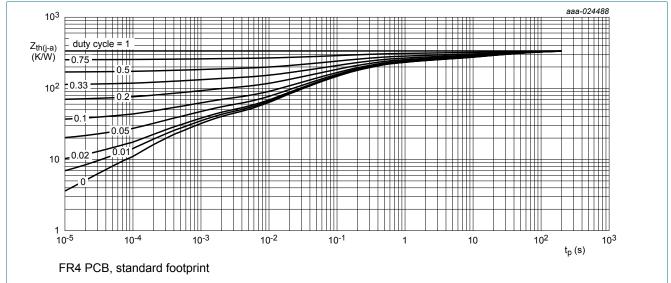


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 100 mA NPN/NPN general-purpose double transistors

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
I _{CBO}	collector-base cut-off	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C	-	-	15	nA
	current	V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C	200	-	450	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA; T _{amb} = 25 °C	-	-	100	mV
		I_C = 100 mA; I_B = 5 mA; T_{amb} = 25 °C	-	-	300	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA; T _{amb} = 25 °C	-	760	-	mV
		I_C = 100 mA; I_B = 5 mA; T_{amb} = 25 °C	-	900	-	mV
V_{BE}	base-emitter voltage	V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C	600	660	725	mV
		V _{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C	-	710	820	mV
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	4	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_{C} = 0 \text{ A}; i_{c} = 0 \text{ A};$ $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$	-	11	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C	100	-	-	MHz
NF	noise figure	V_{CE} = 5 V; I_{C} = 0.2 mA; R_{S} = 2 k Ω ; f = 1 kHz; B = 200 Hz; T_{amb} = 25 °C	-	-	10	dB

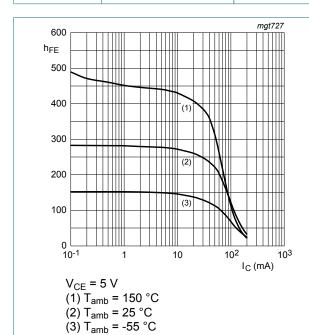


Fig. 3. DC current gain as a function of collector current; typical values

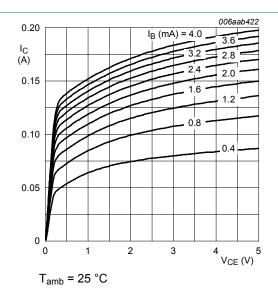


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

45 V, 100 mA NPN/NPN general-purpose double transistors

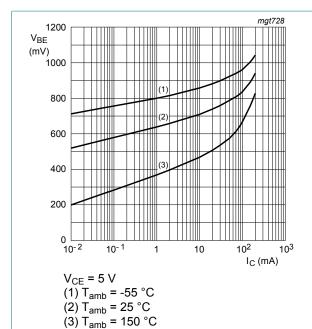
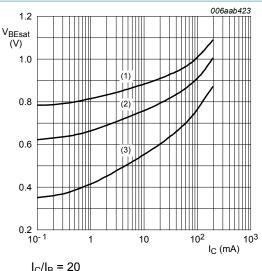


Fig. 5. Base-emitter voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 20$ (1) $T_{amb} = -55 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = 150 \,^{\circ}C$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values

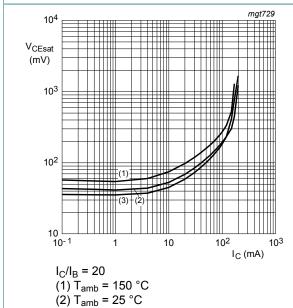


Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

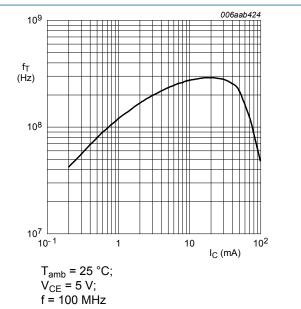


Fig. 8. Transition frequency as a function of collector current; typical values

11. Test information

(3) $T_{amb} = -55$ °C

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

45 V, 100 mA NPN/NPN general-purpose double transistors

12. Package outline

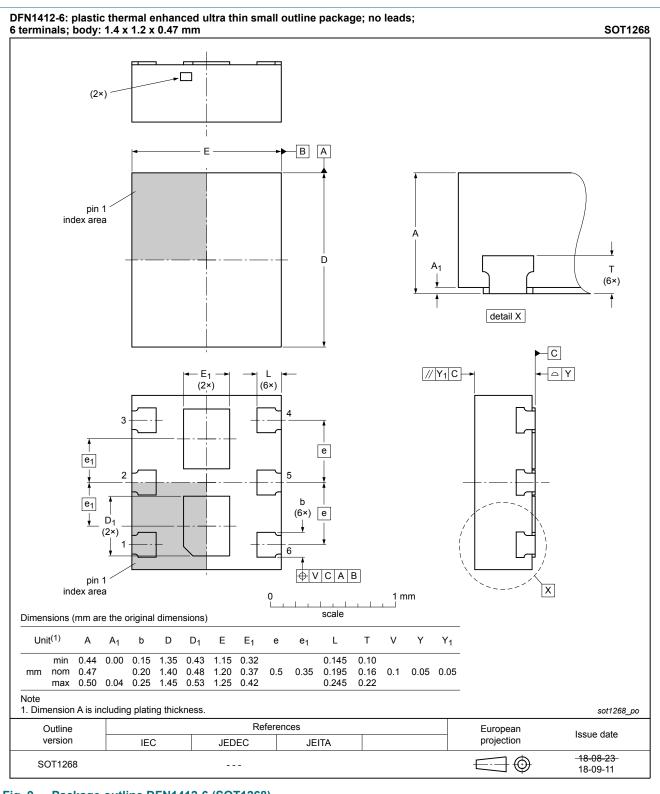
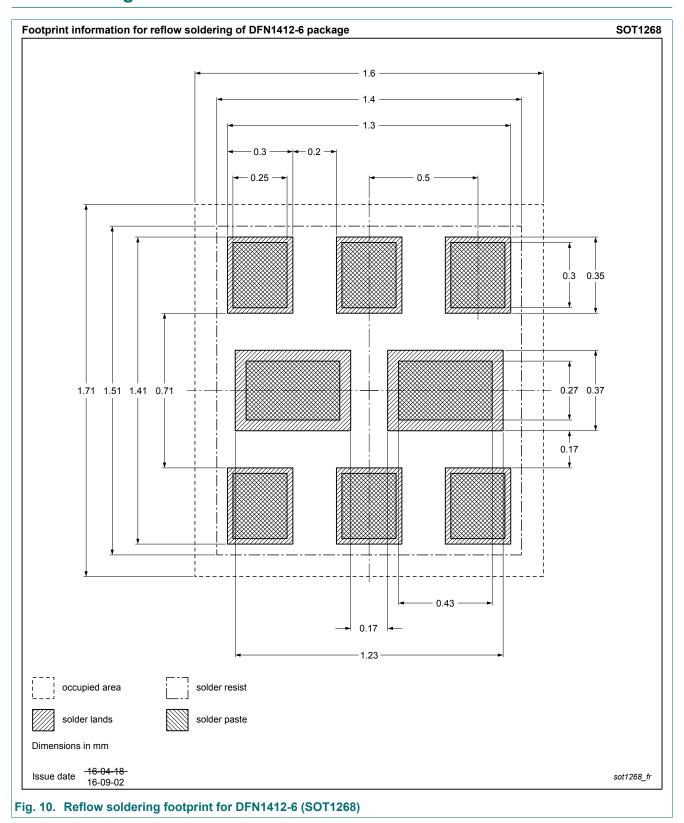


Fig. 9. Package outline DFN1412-6 (SOT1268)

45 V, 100 mA NPN/NPN general-purpose double transistors

13. Soldering



45 V, 100 mA NPN/NPN general-purpose double transistors

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
BC847RA v.2	20180914	Product data sheet	-	BC847RA v.1				
Modifications:	Package outline draw	Package outline drawing updated: Unit T added						
BC847RA v.1	20170613	Product data sheet	-	-				

45 V, 100 mA NPN/NPN general-purpose double transistors

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BC847RA

45 V, 100 mA NPN/NPN general-purpose double transistors

Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	Characteristics	5
11.	Test information	6
12.	Package outline	7
13.	Soldering	8
14.	Revision history	9
	Legal information	

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